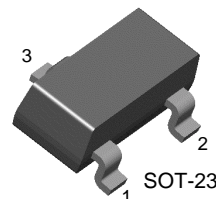


# KST4124

## General Purpose Transistor



1. Base 2. Emitter 3. Collector

## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                   | Value | Units            |
|-----------|-----------------------------|-------|------------------|
| $V_{CBO}$ | Collector-Base Voltage      | 30    | V                |
| $V_{CEO}$ | Collector-Emitter Voltage   | 25    | V                |
| $V_{EBO}$ | Emitter-Base Voltage        | 5     | V                |
| $I_C$     | Collector Current           | 200   | mA               |
| $P_C$     | Collector Power Dissipation | 350   | mW               |
| $T_{STG}$ | Storage Temperature         | 150   | $^\circ\text{C}$ |

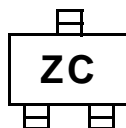
• Refer to KST3904 for graphs

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol               | Parameter                              | Test Condition   | Min.      | Max. | Units |
|----------------------|--|--|-----------|------|-------|
| $BV_{CBO}$           | Collector-Base Breakdown Voltage       | $I_C=10\mu\text{A}, I_E=0$   | 30        |      | V     |
| $BV_{CEO}$           | * Collector-Emitter Breakdown Voltage  | $I_C=1.0\text{mA}, I_B=0$  | 25        |      | V     |
| $BV_{EBO}$           | Emitter-Base Breakdown Voltage         | $I_E=10\mu\text{A}, I_C=0$   | 5         |      | V     |
| $I_{CBO}$            | Collector Cut-off Current              | $V_{CB}=20\text{V}, I_E=0$   |           | 50   | nA    |
| $I_{EBO}$            | Emitter Cut-off Current                | $V_{EB}=3\text{V}, I_C=0$  |           | 50   | nA    |
| $h_{FE}$             | * DC Current Gain                      | $V_{CE}=1\text{V}, I_C=2\text{mA}$<br>$V_{CE}=1\text{V}, I_C=50\text{mA}$                            | 120<br>60 | 360  |       |
| $V_{CE}(\text{sat})$ | * Collector-Emitter Saturation Voltage | $I_C=50\text{mA}, I_B=5.0\text{mA}$  |           | 0.3  | V     |
| $V_{BE}(\text{sat})$ | * Base-Emitter Saturation Voltage      | $I_C=50\text{mA}, I_B=5.0\text{mA}$  |           | 0.95 | V     |
| $f_T$                | Current Gain Bandwidth Product         | $I_C=10\text{mA}, V_{CE}=20\text{V}$<br>$f=100\text{MHz}$  | 300       |      | MHz   |
| $C_{ob}$             | Output Capacitance                     | $V_{CB}=5\text{V}, I_E=0, f=1.0\text{MHz}$   |           | 4    | pF    |
| NF                   | Noise Figure                           | $I_C=100\mu\text{A}, V_{CE}=5\text{V}$<br>$R_S=1\text{K}\Omega$<br>$f=10\text{Hz to }15.7\text{KHz}$ |           | 5    | dB    |

\* Pulse Test:  $PW \leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$

Marking



# Package Dimensions

## SOT-23



Dimensions in Millimeters

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